

## Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

## Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
  - Class Q Military
  - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
  - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

## 54LS10/DM54LS10/DM74LS10 Triple 3-Input NAND Gates

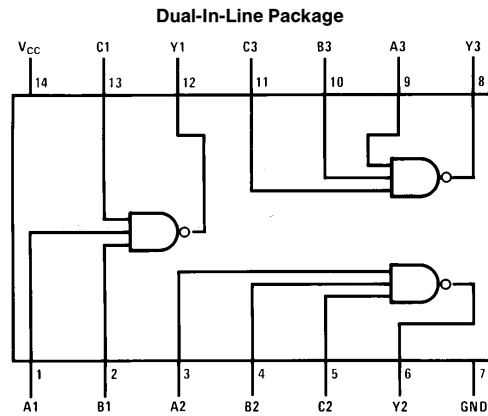
### General Description

This device contains three independent gates each of which performs the logic NAND function.

### Features

- Alternate Military/Aerospace device (54LS10) is available. Contact a National Semiconductor Sales Office/Distributor for specifications.

### Connection Diagram



TL/F/6349-1

Order Number 54LS10DMQB, 54LS10FMQB, 54LS10LMQB,  
DM54LS10J, DM54LS10W, DM74LS10M or DM74LS10N  
See NS Package Number E20A, J14A, M14A, N14A or W14B

### Function Table

$$Y = \overline{ABC}$$

Inputs			Output
A	B	C	Y
X	X	L	H
X	L	X	H
L	X	X	H
H	H	H	L

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

## Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM54LS and 54LS	-55°C to +125°C
DM74LS	0°C to +70°C
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

## Recommended Operating Conditions

Symbol	Parameter	DM54LS10			DM74LS10			Units
		Min	Nom	Max	Min	Nom	Max	
V <sub>CC</sub>	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V <sub>IH</sub>	High Level Input Voltage	2			2			V
V <sub>IL</sub>	Low Level Input Voltage			0.7			0.8	V
I <sub>OH</sub>	High Level Output Current			-0.4			-0.4	mA
I <sub>OL</sub>	Low Level Output Current			4			8	mA
T <sub>A</sub>	Free Air Operating Temperature	-55		125	0		70	°C

## Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
V <sub>I</sub>	Input Clamp Voltage	V <sub>CC</sub> = Min, I <sub>I</sub> = -18 mA			-1.5	V
V <sub>OH</sub>	High Level Output Voltage	V <sub>CC</sub> = Min, I <sub>OH</sub> = Max, V <sub>IL</sub> = Max	DM54 2.5	3.4		V
V <sub>OL</sub>	Low Level Output Voltage	V <sub>CC</sub> = Min, I <sub>OL</sub> = Max, V <sub>IH</sub> = Min	DM54 0.25	0.25	0.4	V
		I <sub>OL</sub> = 4 mA, V <sub>CC</sub> = Min	DM74 0.35	0.35	0.5	
I <sub>I</sub>	Input Current @ Max Input Voltage	V <sub>CC</sub> = Max, V <sub>I</sub> = 7V			0.1	mA
I <sub>IH</sub>	High Level Input Current	V <sub>CC</sub> = Max, V <sub>I</sub> = 2.7V			20	μA
I <sub>IL</sub>	Low Level Input Current	V <sub>CC</sub> = Max, V <sub>I</sub> = 0.4V			-0.36	mA
I <sub>OS</sub>	Short Circuit Output Current	V <sub>CC</sub> = Max (Note 2)	DM54 -20		-100	mA
			DM74 -20		-100	
I <sub>CCH</sub>	Supply Current with Outputs High	V <sub>CC</sub> = Max		0.6	1.2	mA
I <sub>CCL</sub>	Supply Current with Outputs Low	V <sub>CC</sub> = Max		1.8	3.3	mA

## Switching Characteristics at V<sub>CC</sub> = 5V and T<sub>A</sub> = 25°C (See Section 1 for Test Waveforms and Output Load)

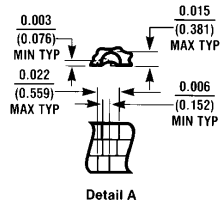
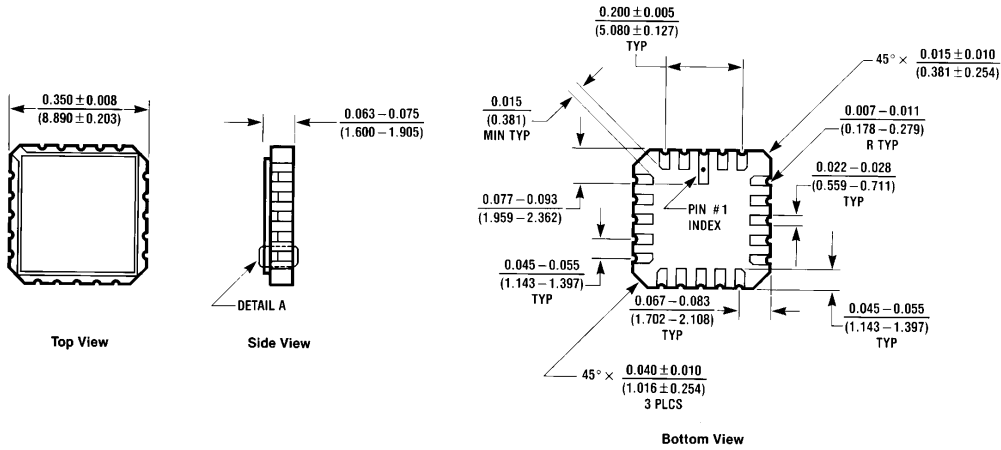
Symbol	Parameter	R <sub>L</sub> = 2 kΩ				Units
		C <sub>L</sub> = 15 pF		C <sub>L</sub> = 50 pF		
		Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	3	10	4	15	ns
t <sub>PHL</sub>	Propagation Delay Time High to Low Level Output	3	10	4	15	ns

Note 1: All typicals are at V<sub>CC</sub> = 5V, T<sub>A</sub> = 25°C.

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

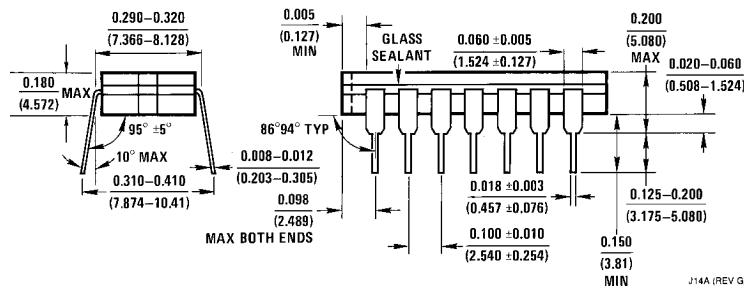
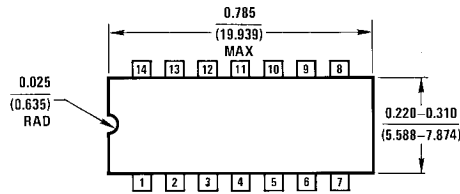


**Physical Dimensions** inches (millimeters)



**Ceramic Leadless Chip Carrier Package (E)**  
**Order Number 54LS10MQB**  
**NS Package Number E20A**

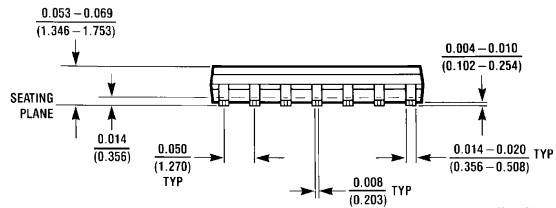
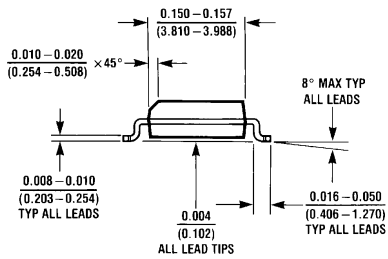
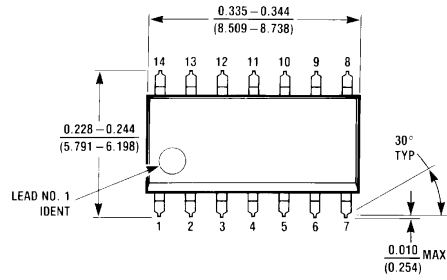
E20A (REV D)



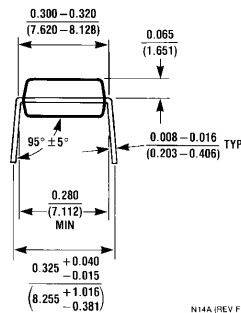
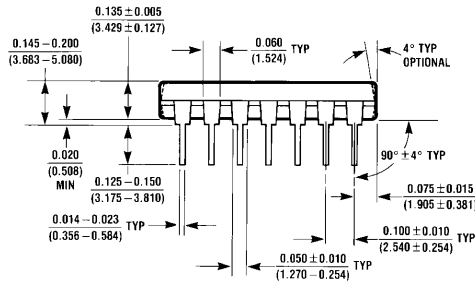
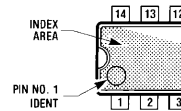
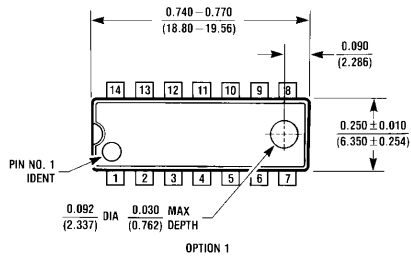
**14-Lead Ceramic Dual-In-Line Package (J)**  
**Order Number 54LS10DMQB or DM54LS10J**  
**NS Package Number J14A**

J14A (REV G)

**Physical Dimensions** inches (millimeters) (Continued)

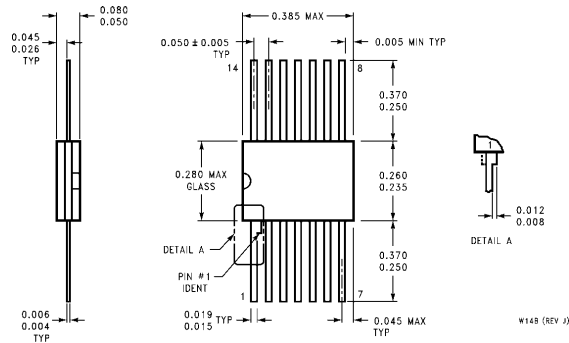


**14-Lead Small Outline Molded Package (M)**  
**Order Number DM74LS10M**  
**NS Package Number M14A**



**14-Lead Molded Dual-In-Line Package (N)**  
**Order Number DM74LS10N**  
**NS Package Number N14A**

**Physical Dimensions** inches (millimeters) (Continued)



**14-Lead Ceramic Flat Package (W)**  
**Order Number 54LS10FMQB or DM54LS10W**  
**NS Package Number W14B**

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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